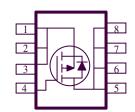
P-Channel 30-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize a high cell density trench process to provide low $r_{DS(on)}$ and to ensure minimal power loss and heat dissipation. Typical applications are DC-DC converters and power management in portable and battery-powered products such as computers, printers, PCMCIA cards, cellular and cordless telephones.

PRODUCT SUMMARY				
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$ $I_D (A)$			
-30	$49 @ V_{GS} = -10V$	-5.7		
	$75 @ V_{GS} = -4.5V$	-5.0		

- $\begin{tabular}{ll} \begin{tabular}{ll} \be$
- Low thermal impedance copper leadframe SOIC-8 saves board space
- Fast switching speed
- High performance trench technology





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter			Maximum	Units		
Drain-Source Voltage			-30	V		
Gate-Source Voltage			±20	V		
Continuous Drain Current ^a	$T_A=25^{\circ}C$	Τ_	±6.5	_		
Continuous Drain Current	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	П	±5.2	A		
Pulsed Drain Current ^b	I_{DM}	±30				
Continuous Source Current (Diode Conduction) ^a	I_S	-1.6	A			
D. D a	$T_A=25^{\circ}C$	D-	3.1	W		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	I D	2.0			
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Case ^a	$t \le 5 \sec$	$R_{ heta JC}$	25	°C/W
Maximum Junction-to-Ambient ^a	t <= 10 sec	$R_{ heta JA}$	40	°C/W

1

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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SPECIFICATIONS (T _A = 25°C UNLESS OTHERWISE NOTED)							
Demonstra	G 1 1	T C W.	Limits			TT .4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$, $I_D = -250 \text{ uA}$	-1				
Gate-Body Leakage	I _{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	I _{DSS}	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zelo Cate Voltage Diam Current	IDSS	$V_{DS} = -24 \text{ V}, V_{GS} = 0 \text{ V}, T_{J} = 55^{\circ}\text{C}$			-5		
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -5 \text{ V}, V_{GS} = -10 \text{ V}$	-30			A	
D : G . C . D : A	l'DS(on)	$V_{GS} = -10 \text{ V}, I_{D} = -5.7 \text{ A}$			49	0	
Drain-Source On-Resistance ^A		$V_{GS} = -4.5 \text{ V}, I_D = -5.0 \text{ A}$			75	mΩ	
Forward Tranconductance ^A	gfs	$V_{DS} = -15 \text{ V}, I_{D} = -5.7 \text{ A}$		19		S	
Diode Forward Voltage	V_{SD}	$I_S = -2.1 \text{ A}, V_{GS} = 0 \text{ V}$		-0.7		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	$V_{DS} = -15 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -5.7 \text{ A}$		6.4			
Gate-Source Charge	Qgs			1.9		nC	
Gate-Drain Charge	Q_{gd}			2.5			
Switching	•				•		
Turn-On Delay Time	$t_{d(on)}$			10			
Rise Time	$t_{\rm r}$	$V_{\rm DD}$ = -15 V, R_L = 15 Ω , I_D = -1 A,		2.8		nS	
Turn-Off Delay Time	t _{d(off)}	$V_{GEN} = -10 \text{ V}, R_G = 6\Omega$		53.6		113	
Fall-Time	t_{f}			46			

Notes

- a. Pulse test: $PW \le 300$ us duty cycle $\le 2\%$.
- b. Guaranteed by design, not subject to production testing.

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Typical Electrical Characteristics (P-Channel)

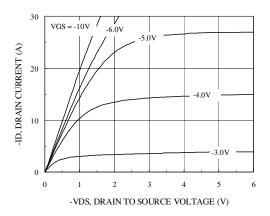


Figure 1. On-Region Characteristics

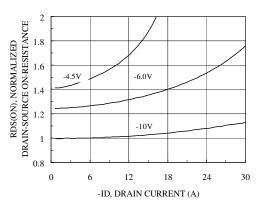


Figure 3. On Resistance Vs Vgs Voltage

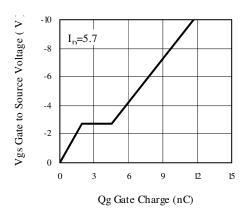


Figure 5. Gate Charge Characteristics

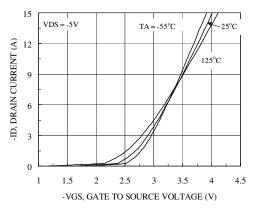


Figure 2. Body Diode Forward Voltage Variation with Source Current and Temperature

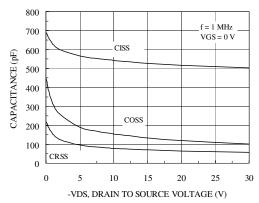


Figure 4. Capacitance Characteristics

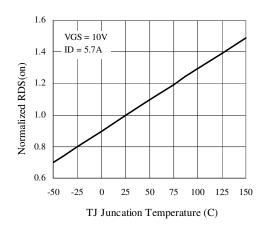


Figure 6. On-Resistance Variation with Temperature

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Typical Electrical Characteristics (P-Channel)

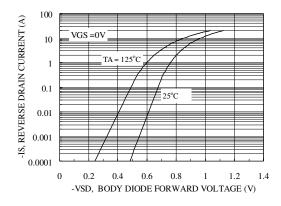


Figure 7. Transfer Characteristics

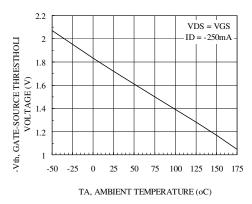


Figure 9. Vth Gate to Source Voltage Vs Temperature

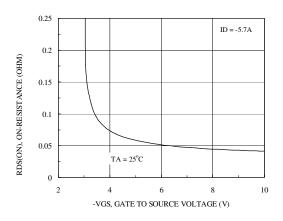


Figure 8. On-Resistance with Gate to Source Voltage

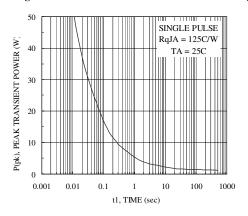


Figure 10. Single Pulse Maximum Power Dissipation



Normalized Thermal Transient Junction to Ambient

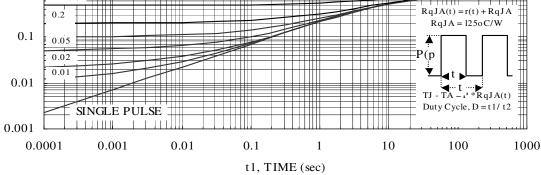
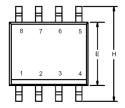


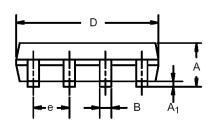
Figure 11. Transient Thermal Response Curve

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Package Information

SO-8: 8LEAD





	MILLIMETERS		INC	HES	
Dim	Min	Max	Min	Max	
Α	1.35	1.75	0.053	0.069	
A ₁	0.10	0.20	0.004	0.008	
В	0.35	0.51	0.014	0.020	
С	0.19	0.25	0.0075	0.010	
D	4.80	5.00	0.189	0.196	
Е	3.80	4.00	0.150	0.157	
е	1.27 BSC		0.050 BSC		
Н	5.80	6.20	0.228	0.244	
h	0.25	0.50	0.010	0.020	
L	0.50	0.93	0.020	0.037	
q	0°	8°	0°	8°	

